

Declaration For U.S. Patent Application

As a below named in	nventor, I hereb	by declare tha	at:	
st and joint invento	iginal, first and r (if plural nar sought on the i	l sole invento mes are listed nvention enti	or (if only one name below) of the subj	w next to my name. e is listed below) or an original, fir ject matter which is claimed and f LE) Technique on ozone water for
the specification of	which			f ·
(Check one of 1, 2, or 3.)	1 is atta	ached hereto.		
	Interna	tional PCT A	pplication No. <u>PC</u> (if applicable	T/JP2003/010254
•	U.S. A ₁	pplication Se	rial No.	as as
	and wa	s amended or	(if applicable	 c)
including the claim(s) I acknowledge the application as define I hereby claim fore application for pater	s), as amended duty to discled in Title 37, Gign priority but or inventor's imed:	by any amen ose informati Code of Feder enefits under certificate lis s certificate h Japan (Country)	idment referred to a ion which is mate ral Regulations, § 1 Title 35, United S sted below and hav	erial to the patentability of this 1.56. States Code, § 119 of any foreign re also identified below any foreign before that of the application for
	(Ivanioer)	(Country)	(Day/Month) 1 cm 1 flee	Yes No
	(Number)	(Country)	(Day/Month/Year Filed	
,	See att	tached list for a	additional prior foreig	gn applications
application listed be not disclosed in the Title 35, United Sta defined in Title 37,	benefit under low and, insof prior United S ates Code, § 1 Code of Feder	Title 35, United at as the substates applicated 12, I acknowed at Regulation and or PCT integrals.	ited States Code, ! oject matter of each tion in the manner vledge the duty to is, § 1.56, which o	§ 120, of any United States patent of the claims of this application is provided by the first paragraph of disclose material information as occurred bet ween the filing date of the of this application:
		•	-	•

KUBOVCIK & KUBOVCIK
Docket No.
Keiko T. Kubovcik, Reg. No. 40,428.

Please direct all communications to the following address:

Kubovcik & Kubovcik The Farragut Building Suite 710 900 17th Street, N.W. Washington, D.C. 20006 Phone: (202) 887-9023 Fax: (202) 887-9093

I hereby declare that all statements made here in of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under Section 1001 of Title 18 of the United States Code and that such willful false statements may jeopardize the validity of the application or any patent issued thereon.

1-00	Full name of first or sole inventor: <u>Makoto Takemura</u>
	Inventor's Signature: Makoto Takomura, Date: 08/03/2025
•	Residence: c/o Sumitomo Mitsubishi Silicon Corporation, 2-1, Shibaura 1-chome, Minato-ku,
	Tokyo 105-8634, Japan JPX
•	Citizenship: Japan
	Post Office Address: Same as residence
0 00	Full name of second inventor: <u>Yasuo Fukuda</u>
2-00	Inventor's Signature: 4000 Fukuda, Date: 08/03/2025
	Residence: c/o Sumitomo Mitsubishi Silicon Corporation, 2-1, Shibaura 1-chome, Minato-ku,
	Tokyo 105-8634, Japan JPX
	Citizenship: Japan
	Post Office Address: Same as residence
2-(Y)	Full name of third inventor: Kazuaki Souda
	Inventor's Signature: Kazuak; Souda. Date: 08/03/2005
•	Residence: c/o Sumitomo Mitsubishi Silicon Corporation, 2-1, Shibaura 1-chome, Minato-ku,
	Tokyo 105-8634, Japan JPX
	Citizenship:Japan
•	Post Office Address: Same as residence

Docket No	,
Full name of fourth inventor: Masaaki Kato	
Inventor's Signature:	Date:
Residence: c/o Puretron Ltd., 2023-15, Fujis	sawa-shi, Kanagawa 252-0816, Japan
Citizenship: Japan	
Post Office Address: Same as residence	
	·
Full name of fifth inventor: <u>Eiji Suhara</u>	
Inventor's Signature:	Date:
Residence: <u>c/o Echo Giken Co., Ltd., 1-13,</u>	Shinmachi 8-chome, Ome-shi, Tokyo 198-0024,
Japan	
Citizenship: <u>Japan</u>	
Post Office Address: Same as residence	

	Deciaration	on For U	.S. Patent Appn	cation
As a below named i	nventor, I hereb	y declare tha	t:	
I believe I am the or t and joint inventor	riginal, first and r (if plural nam sought on the in	sole inventories are listed livention entit	pelow) of the subject ma	to my name. sted below) or an original, firs atter which is claimed and fo echnique on ozone water for
the specification of	which			
(Check one of 1, 2, or 3.)	1 is atta			•
	Internat	tional PCT A	st 11, 2003 pplication No. PCT/JP20 (if applicable)	003/010254
•	U.S. At	oplication Sea	ial No.	as
	and was	s amended on	(if applicable)	·
			(if applicable)	
including the claim(I acknowledge the	s), as amended duty to disclo	by any ameno ose informati	dment referred to above.	ove - identified specification, the patentability of this
application for pate	nt or inventor's nt or inventor's	certificate lis	sted below and have also	Code, § 119 of any foreign identified below any foreign e that of the application for
(List prior		•	4.0.00.000	Priority Claimed
foreign		-	13/08/2002	<u>X</u> Yes No
applications.)	(Number)	(Country)	(Day/Month/Year Filed)	
		(2)		Yes No
	(Number)	(Country)	(Day/Month/Year Filed)	
	(Number)	(Country)	(Day/Month/Year Filed)	YesNo
	,	•	additional prior foreign appl	ications
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application listed be not disclosed in the Title 35, United St defined in Title 37,	elow and, insofa prior United S ates Code, § 1 Code of Feder	ar as the substates applica 12, I acknown al Regulation	ject matter of each of the tion in the manner provi vledge the duty to discle	of any United States patent e claims of this application is ded by the first paragraph of ose material information as ed bet ween the filing date of his application:
	(Application Seria	l No.) (Fil	ing Date) (Status)	
A 171 1				

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D٥	cket No			
Т.	Kubovcik.	Reg.	No.	40.428

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Full name of firs	st or sole inventor:	Makoto Takemura	
Inventor's Signa	ture:		Date:
Residence:	c/o Sumitomo l	Mitsubishi Silicon Co	rporation, 2-1, Shibaura 1-chome, Minato-ku,
	Tokyo 105-8634	4, Japan	
Citizenship:	Japan		
Post Office Add	ress: Same as re	esidence	
Full name of sec	cond inventor: Y	asuo Fukuda	
Inventor's Signa	ture:		Date:
Residence:	c/o Sumitomo	Mitsubishi Silicon Co	orporation, 2-1, Shibaura 1-chome, Minato-ku,
	Tokyo 105-863	34, Japan	
Citizenship:	Japan		
Post Office Add	ress: Same as r	esidence	

Inventor's Signa	ture:		Date:
Residence:	c/o Sumitomo	Mitsubishi Silicon Co	orporation, 2-1, Shibaura 1-chome, Minato-ku,
	Tokyo 105-863	34, Japan	
Citizenship:	Japan		
Post Office Add	ress: Same as r	esidence	

	KUBOVCIK & KUBOV Docket No	-	,	
HUD	Full name of fourth inv		ato	
., 0-	Inventor's Signature:	Massaki	Kato	Date: Aug. 4. 2005
	Residence:c/o I	Puretron Ltd., 202	3-15, Fujisawa-shi	i, Kanagawa 252-0816, Japan JPX
	Citizenship: Jap	an		
	Post Office Address: _			
•	·			
	Full name of fifth inver	ntor: <u>Eiji Suhara</u>		
	Inventor's Signature: _			Date:
	Residence:c/o I	Echo Giken Co., I	td., 1-13, Shinma	chi 8-chome, Ome-shi, Tokyo 198-0024,
	Japar)		
	Citizenship: Jap	an		
	Post Office Address: _	Same as residence	2	

Declaration For U.S. Patent Application

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As a below named in	ventor, I here	by declare that	:	
I believe I am the ori t and joint inventor	iginal, first and (if plural nar ought on the in	d sole inventor nes are listed b nvention entitle	elow) of the subject m	t to my name. sted below) or an original, firs atter which is claimed and for rechnique on ozone water for
the specification of v	vhich			
(Check one of 1, 2, or 3.)	1 is att	ached hereto.	st 11, 2003	as
	Interna		plication No. PCT/JP2	003/010254
	U.S. A	application Seri	ial No(if applicable)	as
			nd the content of the ab Iment referred to above.	ove - identified specification,
			on which is material tal Regulations, § 1.56.	to the patentability of this
application for pater	nt or inventor's	s certificate lis	ted below and have also	s Code, § 119 of any foreign o identified below any foreign re that of the application for
(List prior	2002-235425	Japan	13/08/2002	Priority Claimed X Yes No
foreign applications.)	(Number)	(Country)	(Day/Month/Year Filed)	
	(Number)	(Country)	(Day/Month/Year Filed)	YesNo
		***************************************		Yes No
	(Number)	(Country)	(Day/Month/Year Filed)	
	See at	ttached list for a	dditional prior foreign app	olications
application listed be not disclosed in the Title 35, United Sta defined in Title 37,	low and, inso prior United ates Code, § Code of Fede	far as the sub States applicat 112, I acknow ral Regulation al or PCT inte	ject matter of each of the filter of the manner provoked the duty to discuss, \$ 1.56, which occurred the filting date of the filter of the fil	o), of any United States patent ne claims of this application is yided by the first paragraph of lose material information as red bet ween the filing date of this application:
	(whbitestion 26t)	iai NO.j (Filli	ng Date) (Status)	•

And I hereby appoint as principal attorney and agent Ronald J. Kubovcik, Reg. No. 25,401; and Keiko

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Do	cket No	
Т.	Kubovcik	Reg. No. 40,428

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Full name of first or sole inventor: <u>Ma</u>	koto Takemura
Inventor's Signature:	Date:
Residence: <u>c/o Sumitomo Mitsub</u>	ishi Silicon Corporation, 2-1, Shibaura 1-chome, Minato-ku,
Tokyo 105-8634, Japa	n
Citizenship: Japan	
Post Office Address: Same as residen	ce
Full name of second inventor: Yasuo I	² ukuda · · · · · · · · · · · · · · · · · · ·
	Date:
Residence: <u>c/o Sumitomo Mitsub</u>	nishi Silicon Corporation, 2-1, Shibaura 1-chome, Minato-ku, an
	ce
Full name of third inventor: <u>Kazuaki S</u>	ouda
Inventor's Signature:	Date:
Residence:c/o Sumitomo Mitsub	oishi Silicon Corporation, 2-1, Shibaura 1-chome, Minato-ku,
Tokyo 105-8634, Jap	an
Citizenship: Japan	
Post Office Address: Same as residen	ce ·

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Citizenship:	Japan	
Post Office Addr	ess: Same as residence	
	n inventor: Eiji Suhara	Date: due 5
Inventor's Signati	ure: Egy Jujuzu	
Inventor's Signate Residence:	ure: Egy Wuzu c/o Echo Giken Co., Ltd., 1-13, Shinmachi &	Date: Aug. 5
Inventor's Signate Residence:	ure: Egy Jujuzu	